

NPN Switching Transistor

PXT3904

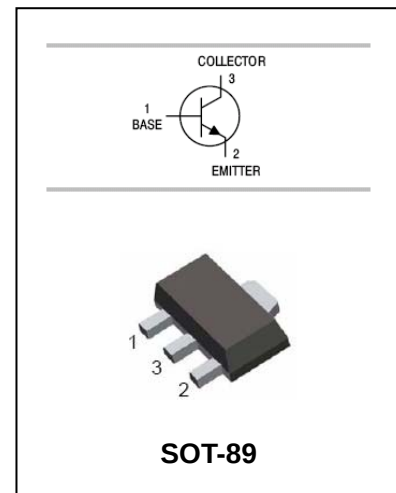
FEATURES

- High current.
- Low voltage.



APPLICATIONS

- High-speed switching.



ORDERING INFORMATION

Type No.	Marking	Package Code
PXT3904	1A	SOT-89

MAXIMUM RATING @ Ta=25°C unless otherwise specified

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	60	V
V_{CEO}	Collector-Emitter Voltage	40	V
V_{EBO}	Emitter-Base Voltage	6	V
I_C	Collector Current -Continuous	100	mA
I_{CM}	Peak Collector Current	200	mA
I_{BM}	Peak Base Current	100	mA
P_{tot}	Total Power Dissipation	0.45	W
T_j	Junction Temperature	150	°C
T_{stg}	Storage Temperature	-65 to +150	°C

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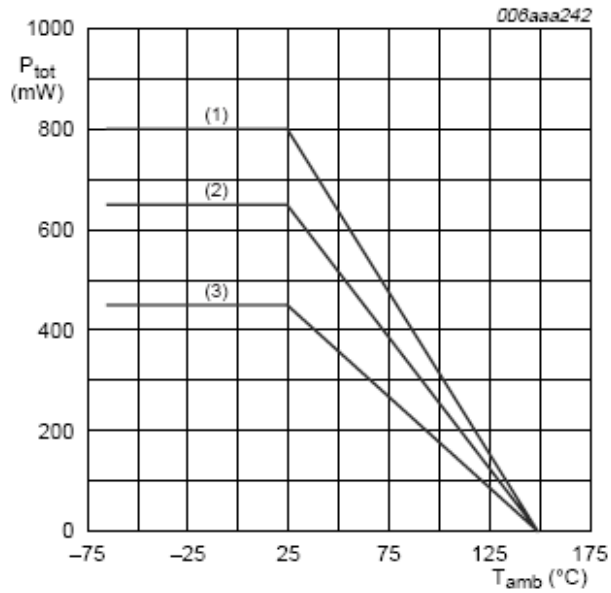
ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=10\mu A, I_E=0$	60		V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=1mA, I_B=0$	40		V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=10\mu A, I_C=0$	6		V
Collector cut-off current	I_{CBO}	$V_{CB}=30V, I_E=0$		50	nA
Emitter cut-off current	I_{EBO}	$V_{EB}=6V, I_C=0$		50	nA
DC current gain	h_{FE}	$V_{CE}=1V, I_C=0.1mA$ $V_{CE}=1V, I_C=1mA$ $V_{CE}=1V, I_C=10mA$ $V_{CE}=1V, I_C=50mA$ $V_{CE}=1V, I_C=100mA$	60 80 100 60 30	300	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=10mA, I_B=1mA$ $I_C=50mA, I_B=5mA$		0.2 0.3	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=10mA, I_B=1mA$ $I_C=50mA, I_B=5mA$	0.65	0.85 0.95	V
Transition frequency	f_T	$V_{CE}=20V, I_C=10mA, f=100MHz$	300		MHz
Collector Capacitance	C_c	$V_{CB}=5V, f=1MHz, I_E=0$		4	pF
Emitter Capacitance	C_e	$V_{EB}=0.5V, f=1MHz, I_C=0$		8	pF
Noise Figure	F	$I_C=100\mu A, V_{CE}=5V, R_S=1k\Omega$ $F=10Hz$ to $7.5kHz$		5	dB

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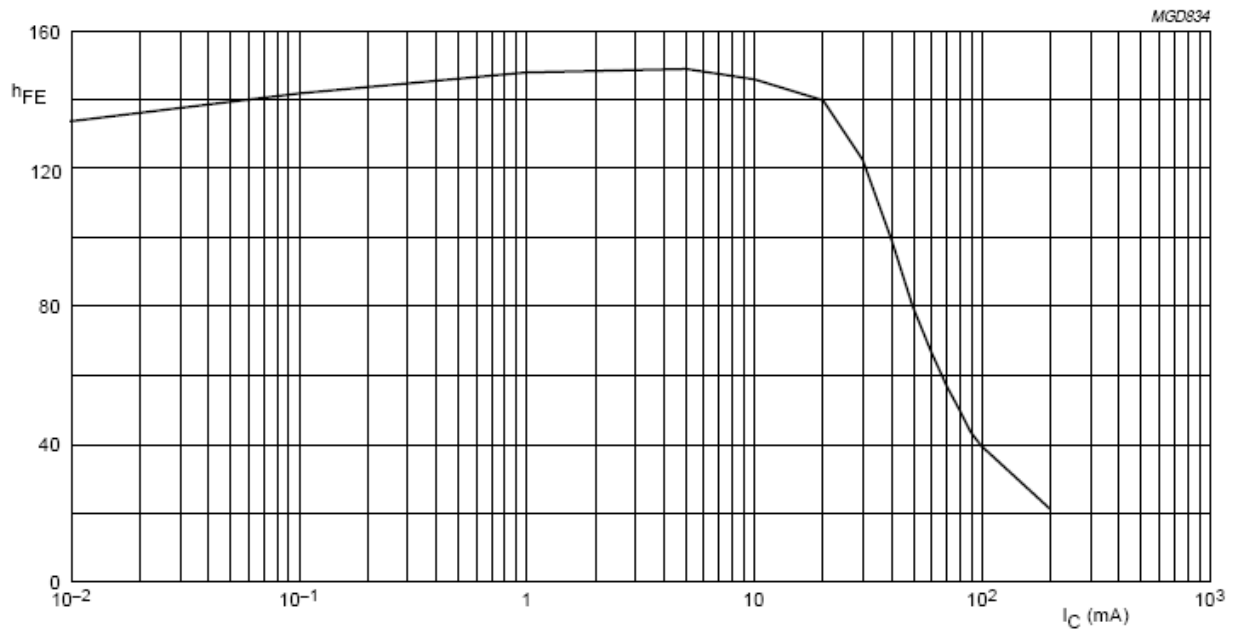
PXT3904

TYPICAL CHARACTERISTICS @ $T_a=25^\circ\text{C}$ unless otherwise specified



- (1) FR4 PCB; 6 cm² mounting pad for collector.
- (2) FR4 PCB; 1 cm² mounting pad for collector.
- (3) FR4 PCB; standard footprint.

Power derating curves.



$V_{CE} = 1\text{ V}$.

DC current gain; typical values.

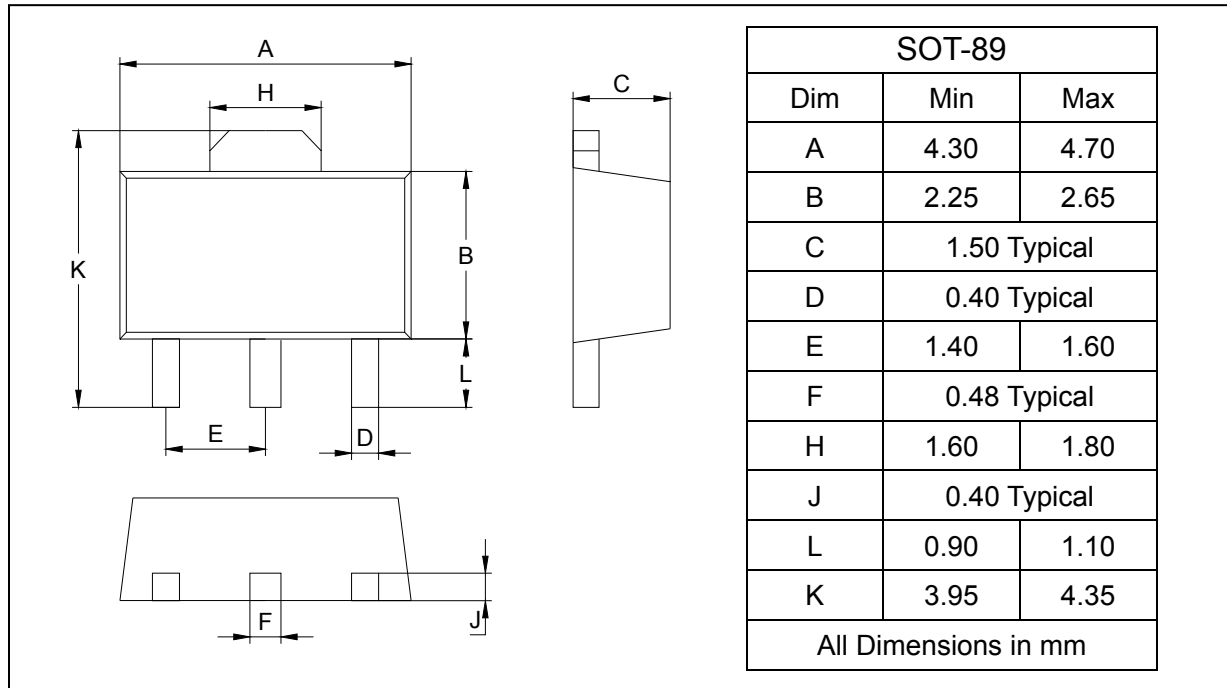
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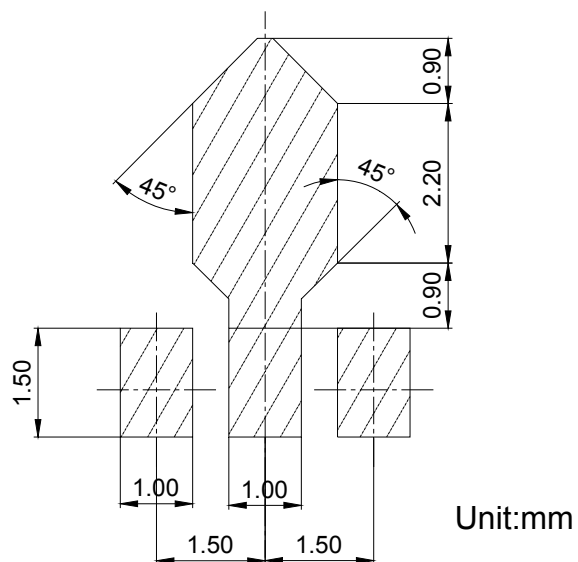
PACKAGE OUTLINE

Plastic surface mounted package

SOT-89



SOLDERING FOOTPRINT



PACKAGE INFORMATION

Device	Package	Shipping
PXT3904	SOT-89	1000/Tape&Reel